



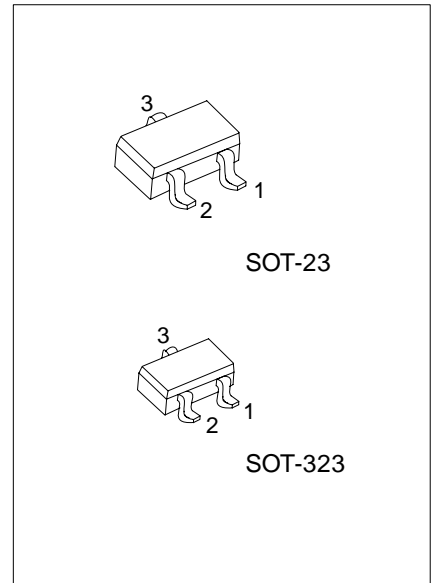
BC846-BC850

NPN SILICON TRANSISTOR

SWITCHING AND AMPLIFIER APPLICATION

■ FEATURES

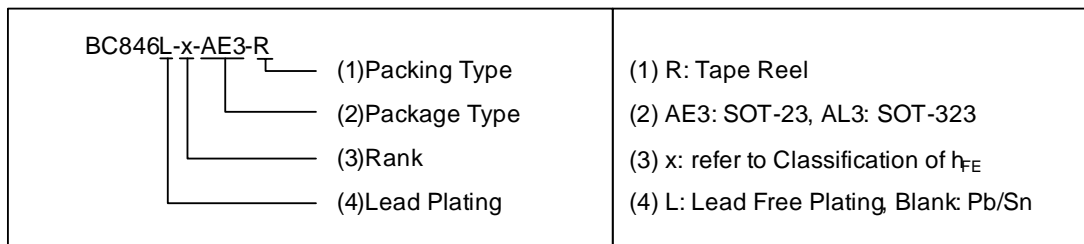
- * Suitable for automatic insertion in thick and thin-film circuits.
- * Complement to BC856 ... BC860



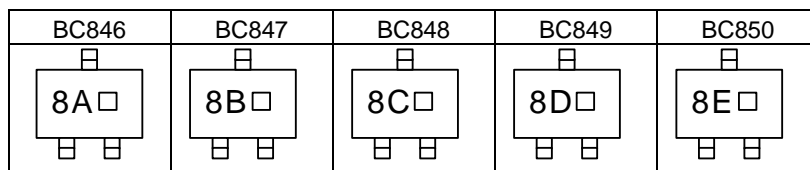
*Pb-free plating product number:
BC846L/BC847L/BC848L/BC849L/BC850L

■ ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
BC846-x-AE3-R	BC846L-x-AE3-R	SOT-23	E	B	C	Tape Reel
BC847-x-AE3-R	BC847L-x-AE3-R	SOT-23	E	B	C	Tape Reel
BC848-x-AE3-R	BC848L-x-AE3-R	SOT-23	E	B	C	Tape Reel
BC849-x-AE3-R	BC849L-x-AE3-R	SOT-23	E	B	C	Tape Reel
BC850-x-AE3-R	BC850L-x-AE3-R	SOT-23	E	B	C	Tape Reel
BC846-x-AL3-R	BC846L-x-AL3-R	SOT-323	E	B	C	Tape Reel
BC847-x-AL3-R	BC847L-x-AL3-R	SOT-323	E	B	C	Tape Reel
BC848-x-AL3-R	BC848L-x-AL3-R	SOT-323	E	B	C	Tape Reel
BC849-x-AL3-R	BC849L-x-AL3-R	SOT-323	E	B	C	Tape Reel
BC850-x-AL3-R	BC850L-x-AL3-R	SOT-323	E	B	C	Tape Reel



■ MARKING



□: Rank Code, refer to Classification of h_{FE}

BC846-BC850

NPN SILICON TRANSISTOR

■ ABSOLUTE MAXIMUM RATING (Ta=25 , unless otherwise specified)

PARAMETER		SYMBOL	VALUE	UNIT
Collector-Base Voltage	BC846	V _{CBO}	80	V
	BC847 / BC850		50	V
	BC848 / BC849		30	V
Collector-Emitter Voltage	BC846	V _{CEO}	65	V
	BC847 / BC850		45	V
	BC848 / BC849		30	V
Emitter-Base Voltage	BC846 / BC847	V _{EBO}	6	V
	BC848 / BC849 / BC850		5	V
Collector Current (DC)		I _C	100	mA
Collector Dissipation	SOT-23	P _D	310	mW
	SOT-323		200	mW
Junction Temperature		T _J	+150	°C
Storage Temperature		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

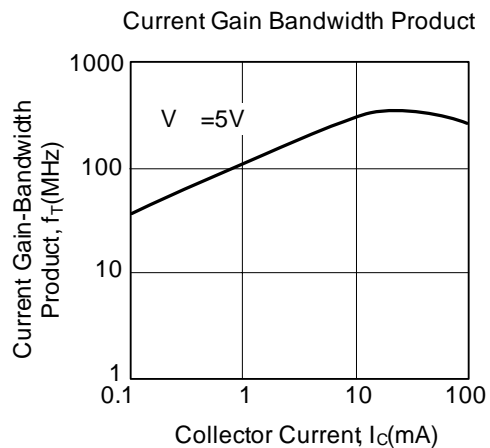
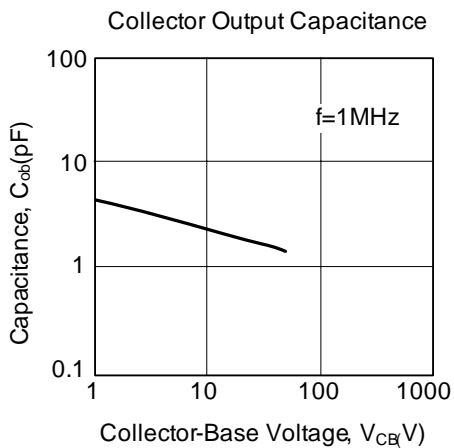
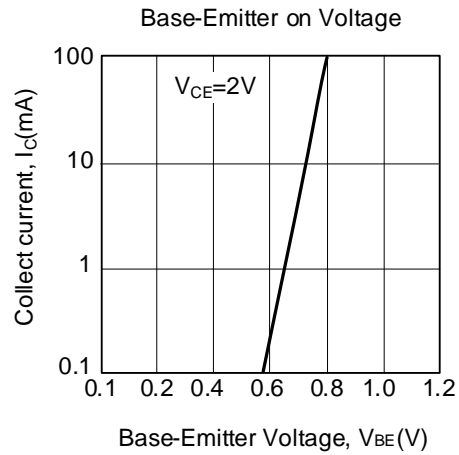
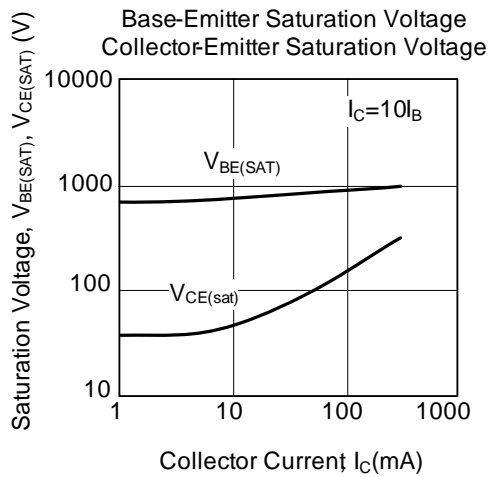
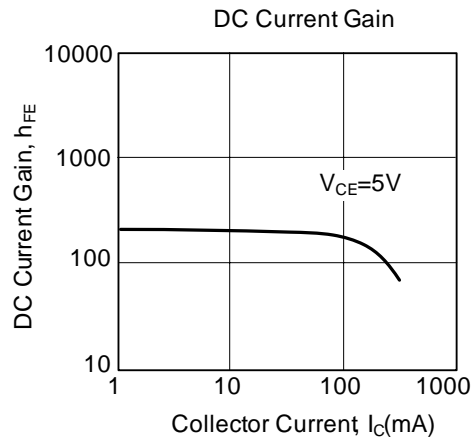
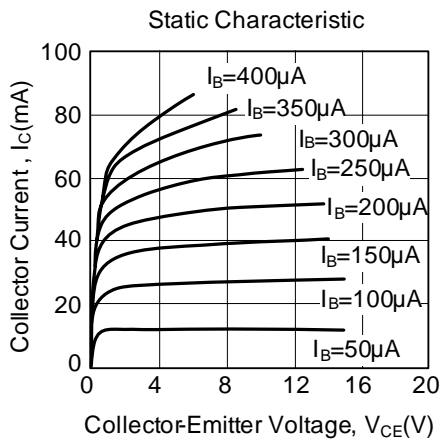
■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current		I _{CBO}	V _{CB} =30V, I _E =0			15	nA
DC Current Gain		h _{FE}	V _{CE} =5.0V, I _C =2.0mA	110		800	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		I _C =10mA, I _B =0.5mA		90	250	mV
			I _C =100mA, I _B =5.0mA		200	600	mV
Collector-Base Saturation Voltage	V _{BE(SAT)}		I _C =10mA, I _B =0.5mA		700		mV
			I _C =100mA, I _B =5.0mA		900		mV
Base-Emitter On Voltage	V _{BE(ON)}		V _{CE} =5.0V, I _C =2.0mA	580	660	700	mV
			V _{CE} =5.0V, I _C =10mA			720	mV
Current Gain Bandwidth Product		f _T	V _{CE} =5.0V, I _C =10mA f=100MHz		300		MHz
Output Capacitance		C _{ob}	V _{CB} =10V, I _E =0, f=1.0MHz		3.5	6	pF
Input Capacitance		C _{ib}	V _{EB} =0.5V, I _C =0, f=1.0MHz		9		pF
Noise Figure	BC846/BC847/BC848	NF	V _{CE} =5V, I _C =200μA, f=1KHz, R _G =2KΩ		2	10	dB
	BC849/BC850				1.2	4	dB
	BC849				1.4	4	dB
	BC850				1.4	3	dB

■ CLASSIFICATION OF h_{FE}

RANK	A	B	C
RANGE	110-220	200-450	420-800

TYPICAL CHARACTERISTICS



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